

20A, 100V - 200V Schottky Barrier Rectifier

FEATURES

- AEC-Q101 qualified available
- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

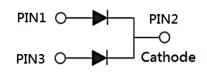
- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.80g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I _F	20	А
V _{RRM}	100 - 200	V
I _{FSM}	150	А
T _{J MAX}	175	°C
Package	TO-220AB	
Configuration	Dual dies	





TO-220AB



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	MBR 20H100CT	MBR 20H150CT	MBR 20H200CT	UNIT
Marking code on the device		MBR 20H100CT	MBR 20H150CT	MBR 20H200CT	
Repetitive peak reverse voltage	V _{RRM}	100	150	200	V
Reverse voltage, total rms value	V _{R(RMS)}	70	105	140	V
Forward current	I _F	20		Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150		А	
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}	1.0 0.5		А	
Peak repetitive forward current (Rated V_R , Square wave, 20KHz)	I _{FRM}	20		А	
Critical rate of rise of off-state voltage	dv/dt	10,000		V/µs	
Junction temperature	TJ	-55 to +175			°C
Storage temperature	T _{STG}	-55 to +175			°C

Notes:

1. tp = 2.0µs, 1.0KHz



MBR20H100CT – MBR20H200CT

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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R _{eJC}	1.5	°C/W

ELECTRICAL SPEC	IFICATIONS	$(T_A = 25^{\circ}C \text{ unless othe})$	rwise noted)			
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode ⁽¹⁾	MBR20H100CT	$I_F = 10A, T_J = 25^{\circ}C$	V _F	-	0.85	V
	MBR20H150CT MBR20H200CT			-	0.88	V
	MBR20H100CT	I _F = 20A, T _J = 25°C		-	0.95	V
	MBR20H150CT MBR20H200CT			-	0.97	V
	MBR20H100CT MBR20H150CT MBR20H200CT	I _F = 10A, T _J = 125°C		-	0.75	V
	MBR20H100CT MBR20H150CT MBR20H200CT	I _F = 20A, T _J = 125°C		-	0.85	V
Reverse current @ rated V_R per diode ⁽²⁾		$T_J = 25^{\circ}C$	- I _R	-	5	μA
		T _J = 125°C		-	2	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
MBR20HxCT	TO-220AB	50 / Tube
MBR20HxCTH	TO-220AB	50 / Tube

Notes:

1. "x" defines voltage from 100V(MBR20H100CT) to 200V(MBR20H200CT)

2. "H" means AEC-Q101 qualified



MBR20H100CT – MBR20H200CT

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

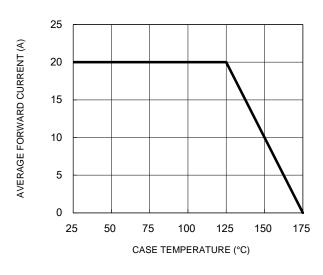


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

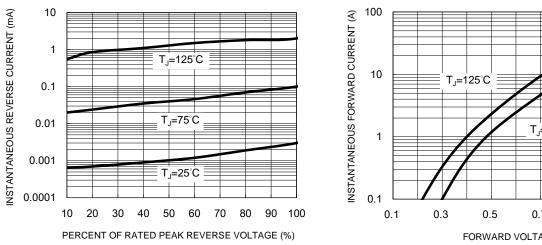


Fig.2 Typical Junction Capacitance 10000

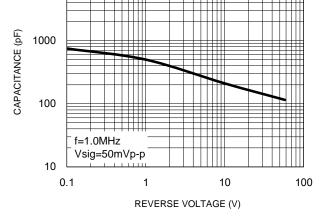


Fig.4 Typical Forward Characteristics

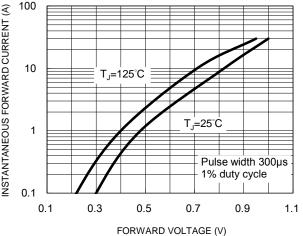
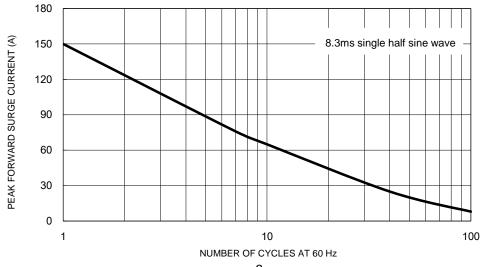


Fig.5 Maximum Non-Repetitive Forward Surge Current





CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

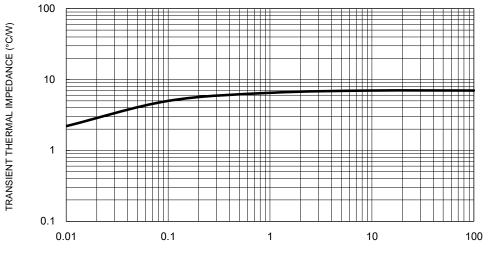
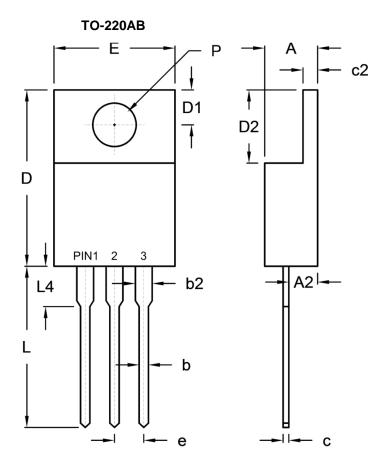


Fig.6 Typical Transient Thermal Impedance

PULSE DURATION (s)

PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit ((inch)
	Min.	Max.	Min.	Max.
A	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
b2	1.14	1.77	0.045	0.070
с	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
E	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
L	13.19	14.79	0.519	0.582
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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